General Purpose Transistor (Isolated Dual Transistors) EMT1/UMT1N/IMT1A

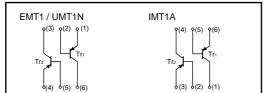
Features

- 1) Two 2SA1037AK chips in a EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.

Structure

Epitaxial planar type PNP silicon transistor

Equivalent circuit



The following characteristics apply to both $\ensuremath{\text{Tr}}\xspace_1$ and $\ensuremath{\text{Tr}}\xspace_2$.

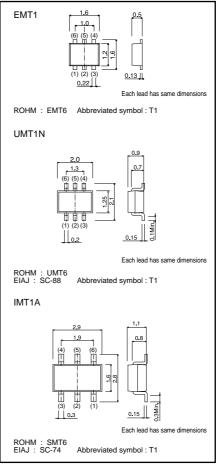
• Absolute maximum ratings (Ta = 25° C)

Symbol Limits		Unit	
Vсво	-60	V	
Vceo	-50	V	
Vево	-6	V	
lc	-150	mA	
l Da	150 (TOTAL)	mW *1 *2	
- PC	300 (TOTAL)		
Tj	150	°C	
Tstg	-55 to +150	°C	
	Vсво Vсео Vево Ic I Pc Tj	VCBO -60 VCEO -50 VEBO -6 Ic -150 Pc 150 (TOTAL) 300 (TOTAL) 150	

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

Dimensions (Unit : mm)



Transistors

•Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic = -50μA	
Collector-emitter breakdown voltage	BVCEO	-50	-	-	V	Ic = -1mA	
Emitter-base breakdown voltage	ВУево	-6	-	-	V	Ιε = -50μA	
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb = -60V	
Emitter cutoff current	Іево	-	-	-0.1	μΑ	Veb = -6V	
Collector-emitter saturation voltage	VCE(sat)	-	-	-0.5	V	Ic/Iв = -50mA/-5mA	
DC current transfer ratio	hfe	120	-	560	-	$V_{CE} = -6V, I_{C} = -1mA$	
Transition frequency	fт	-	140	-	MHz	Vce = -12V, Ie = 2mA, f = 100MHz	
Output capacitance	Cob	-	4	5	pF	Vcb = -12V, IE = 0A, f = 1MHz	

Packaging specifications

	Package	Taping			
	Code	T2R	TN	T110	
Туре	Basic ordering unit (pieces)	8000	3000	3000	
EMT1		0	-	-	
UMT1N		-	0	-	
IMT1A		-	-	0	

Electrical characteristic curves

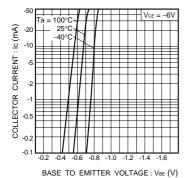
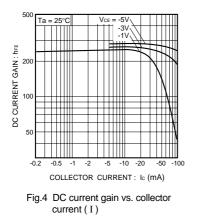
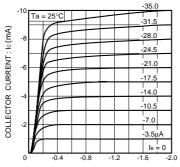


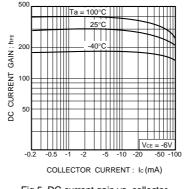
Fig.1 Grounded emitter propagation characteristics

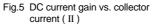


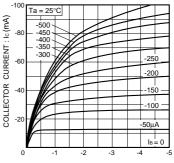


COLLECTOR TO EMITTER VOLTAGE : VCE (V)

Fig.2 Grounded emitter output characteristics (I)

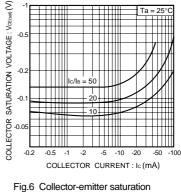






COLLECTOR TO EMITTER VOLTAGE : VCE (V)

Fig.3 Grounded emitter output characteristics (II)





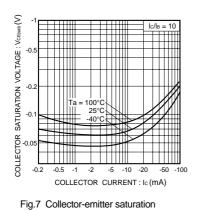
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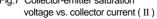
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2/3

Transistors

EMT1 / UMT1N / IMT1A





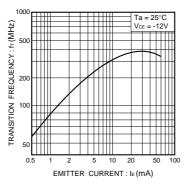
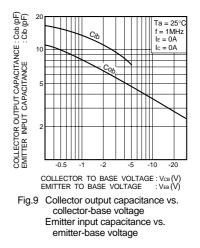


Fig.8 Gain bandwidth product vs. emitter current



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Appendix1-Rev2.0

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